

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC1655C

SILICON MONOLITHIC BIPOLAR INTEGRATED CIRCUIT

WIDE BAND AMPLIFIER

DESCRIPTION

The μ PC1655C is a silicon monolithic integrated circuit especially designed as a wide band amplifier converging HF band through UHF band.

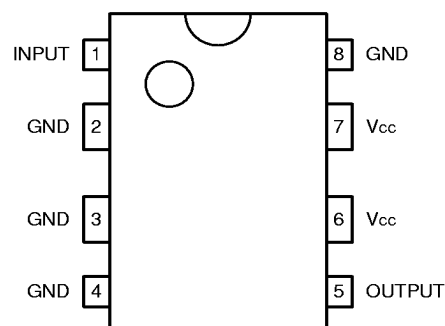
FEATURES

- Excellent frequency response : 800 MHz TYP. @ 3 dB down
- High power gain : 18 dB TYP. @ $f = 500$ MHz
- Low voltage operation : $V_{CC} = 5$ V
- Small package

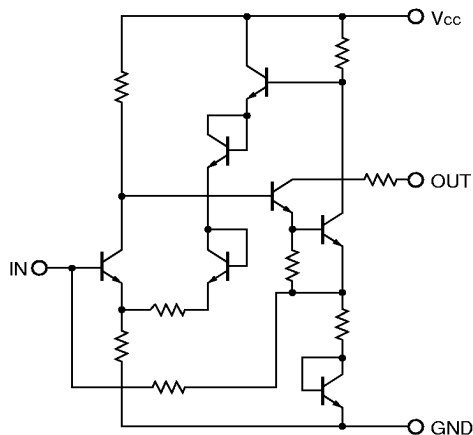
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Supply Voltage	V_{CC}	7	V
Total Power dissipation	P_T	600	mW
Operating Temperature	T_{opt}	-20 to +75	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to +125	$^\circ\text{C}$

CONNECTION DIAGRAM (Top View)



EQUIVALENT CIRCUIT



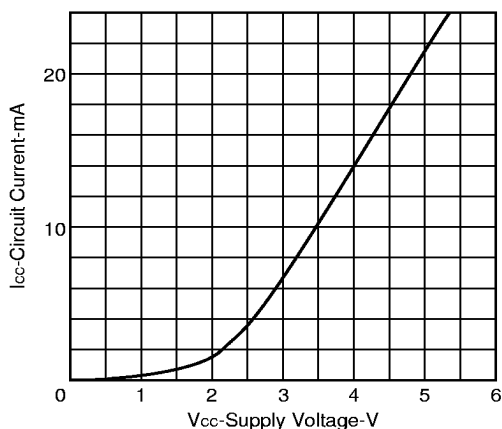
ELECTRICAL CHARACTERISTICS ($T_A = -25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Circuit Current	I_{CC}	15	20	25	mA	$V_{CC} = 5$ V
Gain	G_v	16	18	20	dB	$V_{CC} = 5$ V, $f = 500$ MHz
Noise Figure	NF		5.5	6.5	dB	$V_{CC} = 5$ V, $f = 500$ MHz
Band Width	BW	800	900		MHz	$V_{CC} = 5$ V, 3 dB down
Isolation	I_{SO}	24	27		dB	$V_{CC} = 5$ V, $f = 500$ MHz
Input Return Loss	$ S_{11} $	15	18		dB	$V_{CC} = 5$ V, $f = 500$ MHz
Output Return Loss	$ S_{22} $	10	13		dB	$V_{CC} = 5$ V, $f = 500$ MHz
Maximum Output Level	P_o	3	5		dBm	$V_{CC} = 5$ V, $f = 500$ MHz

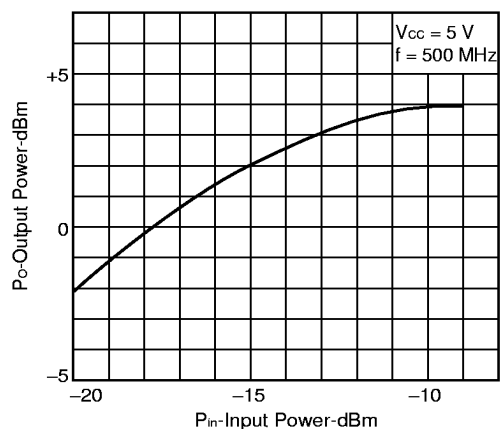
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TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

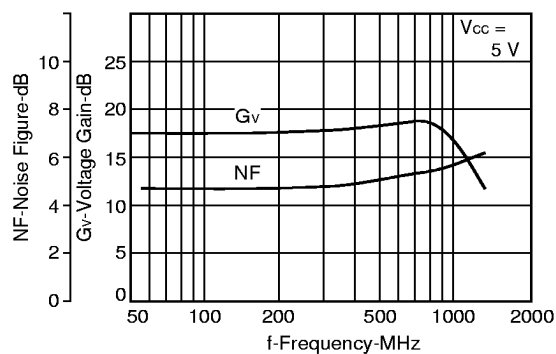
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



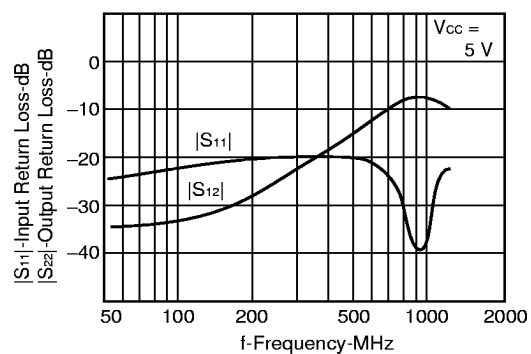
INPUT POWER vs. OUTPUT POWER



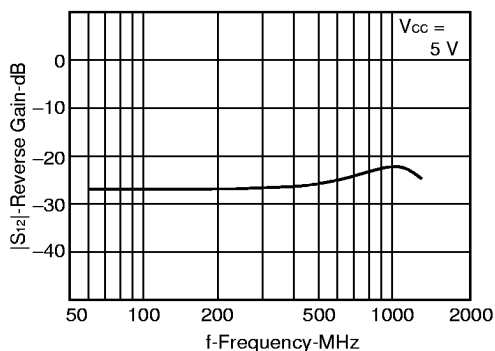
NOISE FIGURE AND VOLTAGE GAIN vs. FREQUENCY



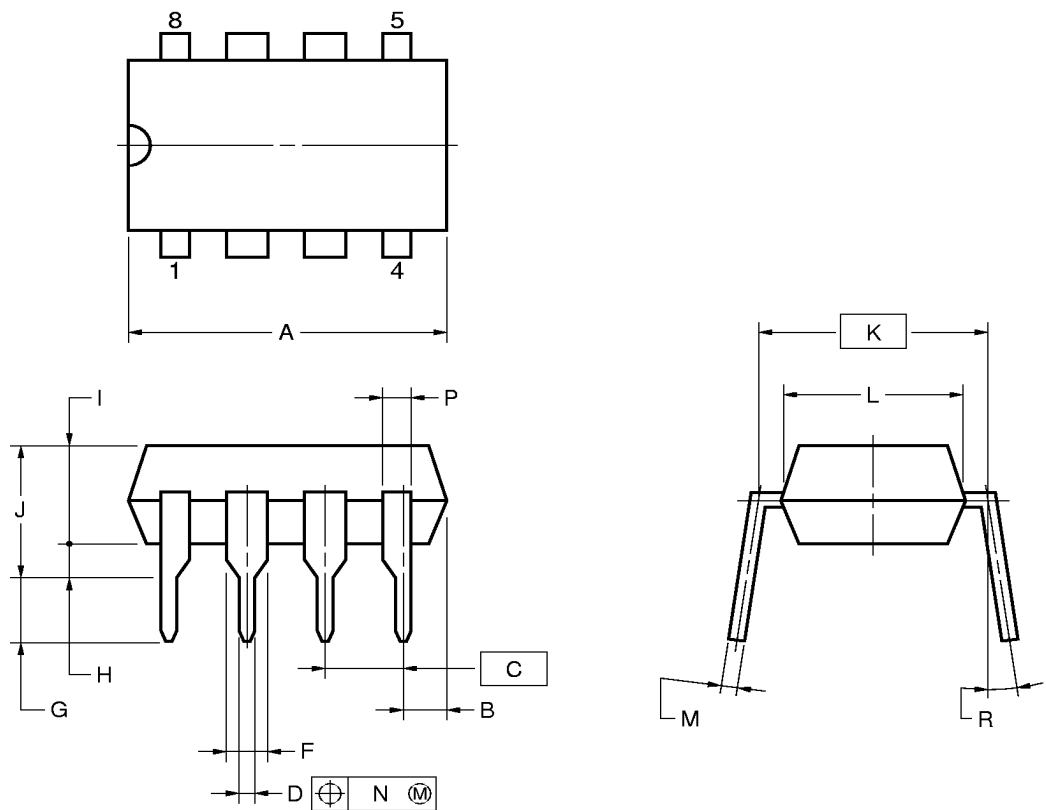
INPUT AND OUTPUT RETURN LOSS vs. FREQUENCY



REVERSE GAIN vs. FREQUENCY



8PIN PLASTIC DIP (300 mil)



NOTES

- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
A	10.16 MAX.	0.400 MAX.
B	1.27 MAX.	0.050 MAX.
C	2.54 (T.P.)	0.100 (T.P.)
D	0.50±0.10	0.020 ^{+0.004} _{-0.005}
F	1.4 MIN.	0.055 MIN.
G	3.2±0.3	0.126±0.012
H	0.51 MIN.	0.020 MIN.
I	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
M	0.25 ^{+0.10} _{-0.05}	0.010 ^{+0.004} _{-0.003}
N	0.25	0.01
P	0.9 MIN.	0.035 MIN.
R	0~15°	0~15°

P8C-100-300B,C-1